

CBTD3306

Dual bus switch with level shifting

Rev. 8 — 1 May 2012

Product data sheet

1. General description

The CBTD3306 dual FET bus switch features independent line switches. Each switch is disabled when the associated output enable (nOE) input is HIGH.

The CBTD3306 is characterized for operation from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$.

2. Features and benefits

- Designed to be used in 5 V to 3.3 V level shifting applications with internal diode
- $5\text{ }\Omega$ switch connection between two ports
- TTL-compatible input levels
- Multiple package options
- Latch-up protection exceeds 100 mA per JESD78B
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ CDM JESD22-C101E exceeds 1000 V

3. Ordering information

Table 1. Ordering information

Type number	Package		
	Name	Description	Version
CBTD3306D	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1
CBTD3306PW	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 4.4 mm	SOT530-1
CBTD3306GT	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $1 \times 1.95 \times 0.5\text{ mm}$	SOT833-1
CBTD3306GM	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5\text{ mm}$	SOT902-2

4. Marking

Table 2. Marking codes

Type number	Marking code
CBTD3306D	CBTD3306
CBTD3306PW	D306
CBTD3306GT	W06
CBTD3306GM	W06



5. Functional diagram

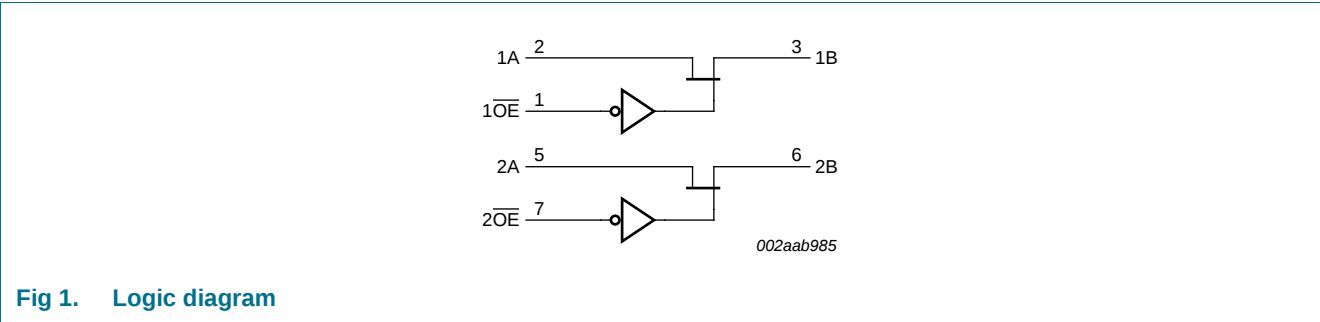


Fig 1. Logic diagram

6. Pinning information

6.1 Pinning

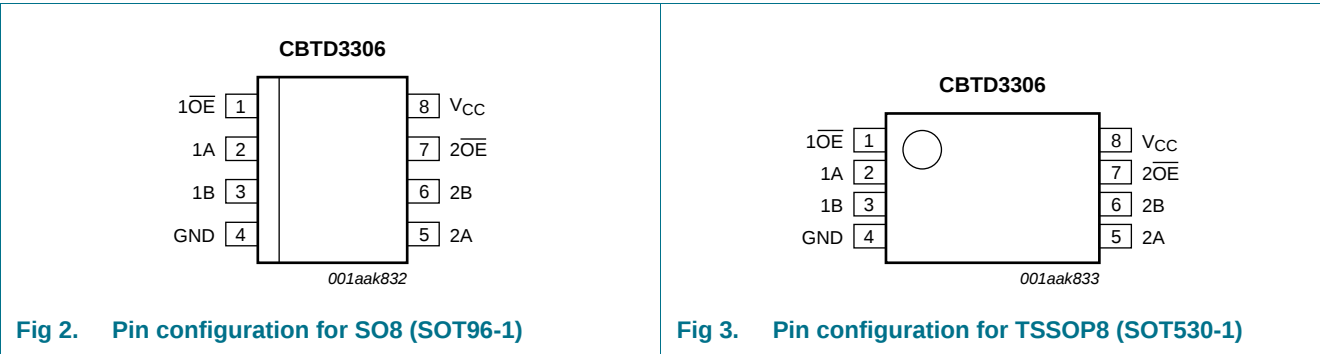


Fig 2. Pin configuration for SO8 (SOT96-1)

Fig 3. Pin configuration for TSSOP8 (SOT530-1)

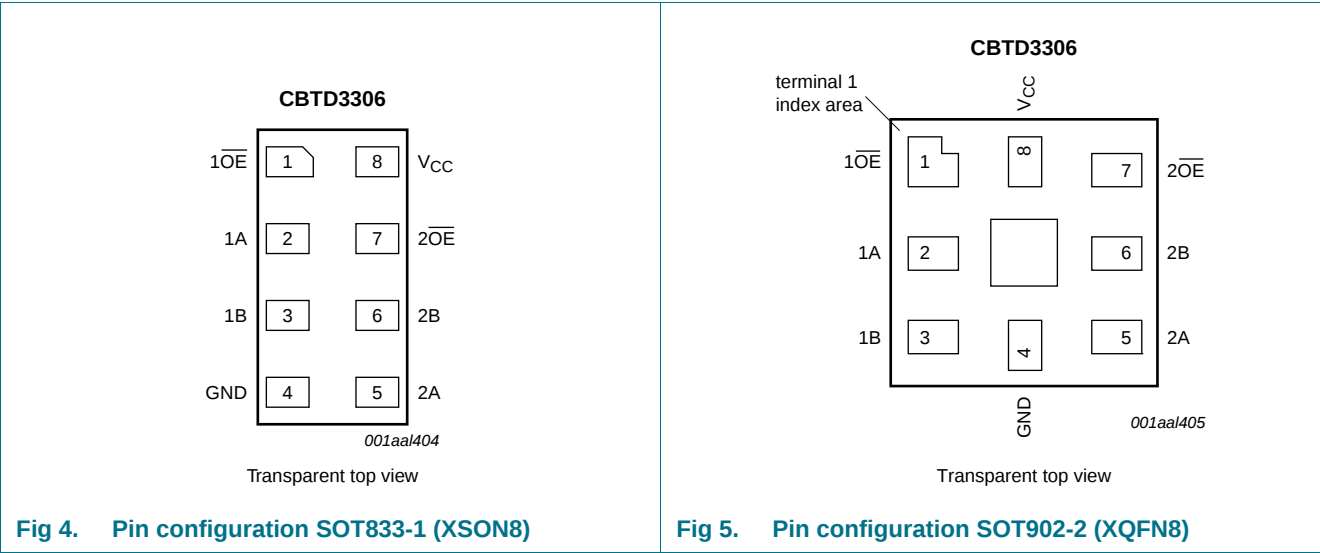


Fig 4. Pin configuration SOT833-1 (XSON8)

Fig 5. Pin configuration SOT902-2 (XQFN8)

6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
$\overline{1OE}, \overline{2OE}$	1, 7	output enable input
1A, 2A	2, 5	data input/output (A port)
1B, 2B	3, 6	data input/output (B port)
GND	4	ground (0 V)
V _{CC}	8	positive supply voltage

7. Functional description

Table 4. Function selection^[1]

Input	Input/output
$\overline{nOE}$	nA, nB
L	nA = nB
H	Z

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).^[1]

T_{amb} = -40 °C to +85 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
V _I	input voltage		^[2] -0.5	+7.0	V
I _{SW}	switch current		-	128	mA
I _{IK}	input clamping current	V _{I/O} = 0 V	-50	-	mA
T _{stg}	storage temperature		-65	+150	°C

[1] Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under [Section 9](#), is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

[2] The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{CC}	supply voltage		4.5	-	5.5	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
T _{amb}	ambient temperature	operating in free air	-40	-	+85	°C

10. Static characteristics

Table 7. Static characteristics

Voltages are referenced to GND (ground = 0 V).

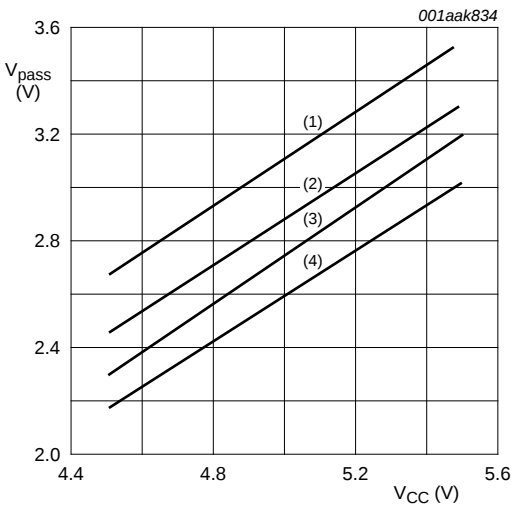
Symbol	Parameter	Conditions	T _{amb} = -40 °C to +85 °C			Unit
			Min	Typ ^[1]	Max	
V _{IK}	input clamping voltage	V _{CC} = 4.5 V; I _I = -18 mA	-	-	-1.2	V
I _I	input leakage current	V _{CC} = 5.5 V; V _I = GND or 5.5 V	-	-	±1	μA
I _{CC}	supply current	V _{CC} = 5.5 V; I _{SW} = 0 mA; V _I = V _{CC} or GND	-	-	1.5	mA
V _{pass}	pass voltage	see Figure 6 to Figure 10	-	-	-	V
ΔI _{CC}	additional supply current	per input pin; V _{CC} = 5.5 V; one input at 3.4 V, other inputs at V _{CC} or GND ^[2]	-	-	2.5	mA
C _I	input capacitance	control pin; V _I = 3 V or 0 V	-	3.2	-	pF
C _{io(off)}	off-state input/output capacitance	port off; V _I = 3 V or 0 V; $\overline{\text{nOE}} = \text{V}_{\text{CC}}$	-	6.5	-	pF
R _{ON}	ON resistance	V _{CC} = 4.5 V; V _I = 0 V; I _I = 64 mA ^[3]	-	3.6	5	Ω
		V _{CC} = 4.5 V; V _I = 0 V; I _I = 30 mA ^[3]	-	3.6	5	Ω
		V _{CC} = 4.5 V; V _I = 2.4 V; I _I = 15 mA ^[3]	-	17	35	Ω

[1] All typical values are at V_{CC} = 5 V, T_{amb} = 25 °C.

[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

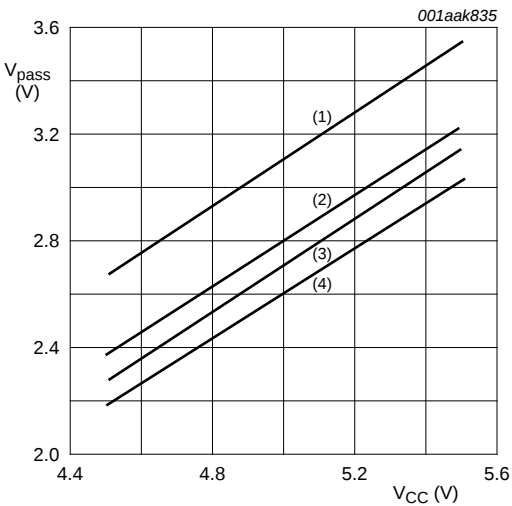
[3] Measured by the voltage drop between the nA and the nB terminals at the indicated current through the switch. ON resistance is determined by the lowest voltage of the two (nA or nB) terminals.

10.1 Typical pass voltage graphs



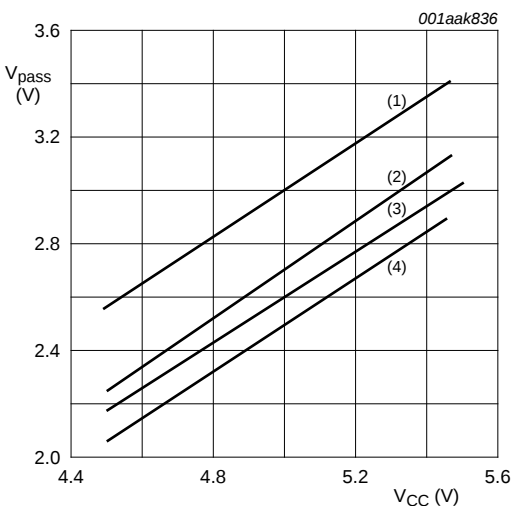
- (1) $I_{SW} = 100 \mu A$
- (2) $I_{SW} = 6 \text{ mA}$
- (3) $I_{SW} = 12 \text{ mA}$
- (4) $I_{SW} = 24 \text{ mA}$

Fig 6. Pass voltage versus supply voltage;
 $T_{amb} = 85 \text{ }^{\circ}\text{C}$ (typical)



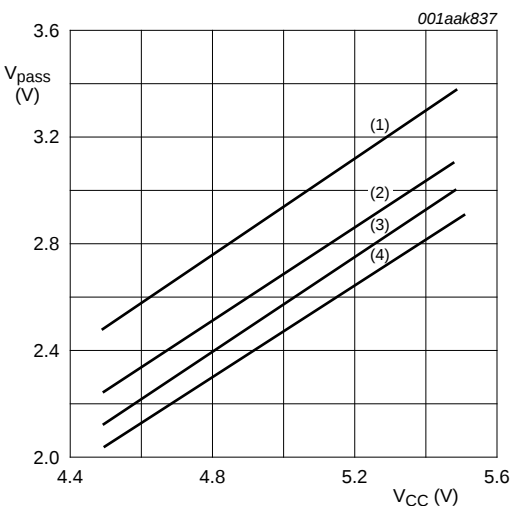
- (1) $I_{SW} = 100 \mu A$
- (2) $I_{SW} = 6 \text{ mA}$
- (3) $I_{SW} = 12 \text{ mA}$
- (4) $I_{SW} = 24 \text{ mA}$

Fig 7. Pass voltage versus supply voltage;
 $T_{amb} = 70 \text{ }^{\circ}\text{C}$ (typical)



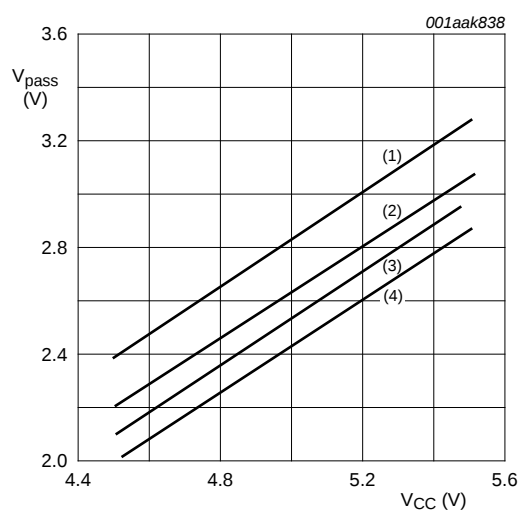
- (1) $I_{SW} = 100 \mu A$
- (2) $I_{SW} = 6 \text{ mA}$
- (3) $I_{SW} = 12 \text{ mA}$
- (4) $I_{SW} = 24 \text{ mA}$

Fig 8. Pass voltage versus supply voltage;
 $T_{amb} = 25 \text{ }^{\circ}\text{C}$ (typical)



- (1) $I_{SW} = 100 \mu A$
- (2) $I_{SW} = 6 \text{ mA}$
- (3) $I_{SW} = 12 \text{ mA}$
- (4) $I_{SW} = 24 \text{ mA}$

Fig 9. Pass voltage versus supply voltage;
 $T_{amb} = 0 \text{ }^{\circ}\text{C}$ (typical)



- (1) $I_{SW} = 100 \mu A$
- (2) $I_{SW} = 6 \text{ mA}$
- (3) $I_{SW} = 12 \text{ mA}$
- (4) $I_{SW} = 24 \text{ mA}$

Fig 10. Pass voltage versus supply voltage; $T_{amb} = -40^\circ \text{C}$ (typical)

11. Dynamic characteristics

Table 8. Dynamic characteristics

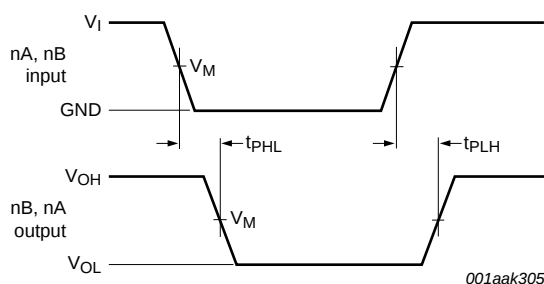
Voltages are referenced to GND (ground = 0 V). For test circuit see [Figure 13](#).

Symbol	Parameter	Conditions	T _{amb} = –40 °C to +85 °C			Unit
			Min	Typ	Max	
t _{pd}	propagation delay	nA, nB to nB, nA; see Figure 11 V _{CC} = 5.0 V ± 0.5 V	[1][2]	-	0.25	ns
t _{en}	enable time	nOE to nA or nB; see Figure 12 V _{CC} = 5.0 V ± 0.5 V	[2]	-	5.4	ns
t _{dis}	disable time	nOE to nA or nB; see Figure 12 V _{CC} = 5.0 V ± 0.5 V	[2]	-	4.9	ns

[1] The propagation delay is the calculated RC time constant of the typical ON resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.
t_{en} is the same as t_{PZL} and t_{PZH}.
t_{dis} is the same as t_{PLZ} and t_{PHZ}.

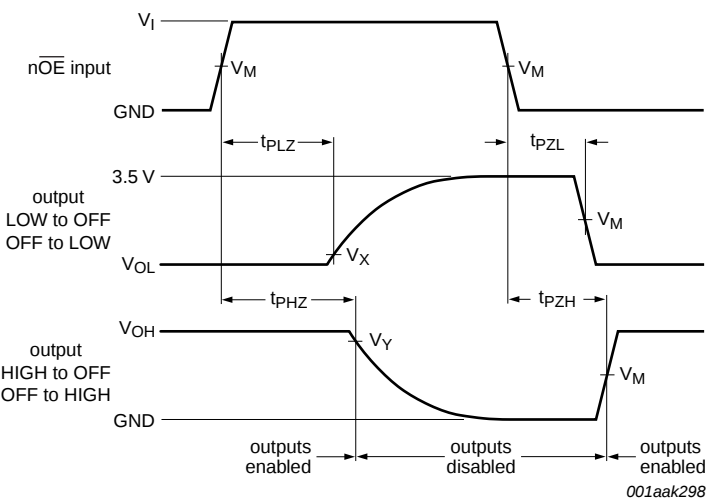
12. Waveforms



Measurement points are given in [Table 9](#).

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 11. The data input (nA, nB) to output (nB, nA) propagation delay times



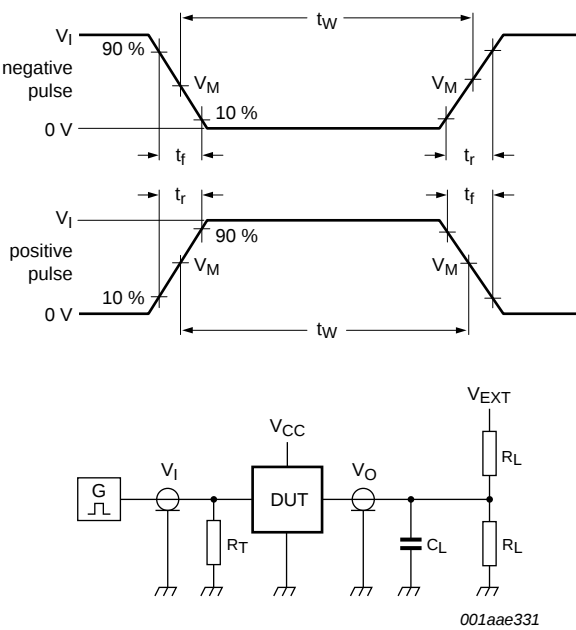
Measurement points are given in [Table 9](#).
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 12. Enable and disable times

Table 9. Measurement points

Supply voltage	Input		Output		
V_{CC}	V_I	V_M	V_M	V_X	V_Y
$V_{CC} = 5.0\text{ V} \pm 0.5\text{ V}$	GND to 3.0 V	1.5 V	1.5 V	$V_{OL} + 0.3\text{ V}$	$V_{OH} - 0.3\text{ V}$

13. Test information



Test data is given in [Table 10](#).
All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$; $Z_o = 50\ \Omega$.
The outputs are measured one at a time with one transition per measurement.
Definitions for test circuit:
 R_L = Load resistance.
 C_L = Load capacitance including jig and probe capacitance.
 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.
 V_{EXT} = External voltage for measuring switching times.

Fig 13. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Input		Load		V _{EXT}		
	V _I	t _r , t _f	C _L	R _L	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}
V _{CC} = 5.0 V ± 0.5 V	GND to 3.0 V	≤ 2.5 ns	50 pF	500 Ω	open	7.0 V	open

14. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

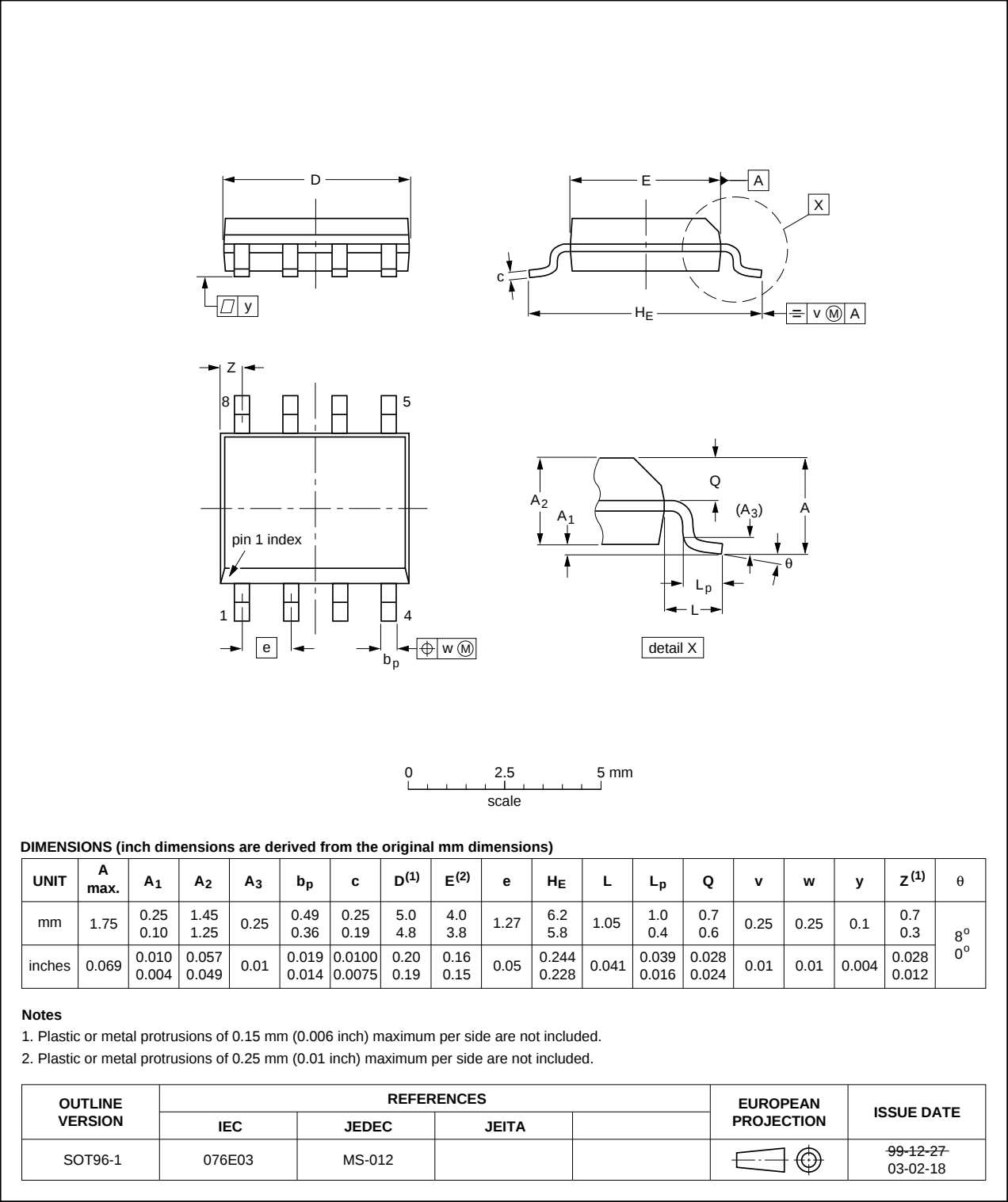


Fig 14. Package outline SOT96-1 (SO8)

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 4.4 mm

SOT530-1

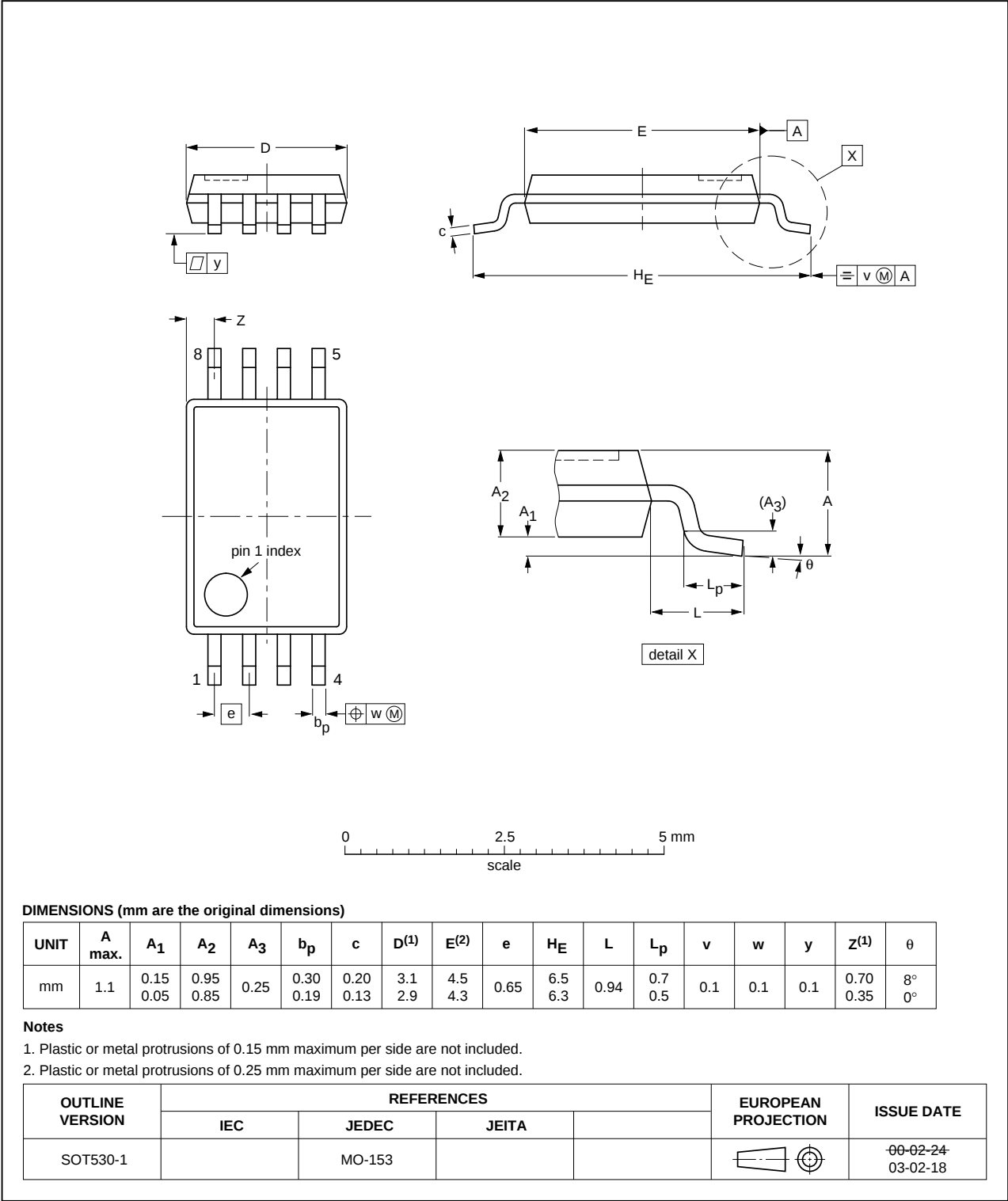


Fig 15. Package outline SOT530-1 (TSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

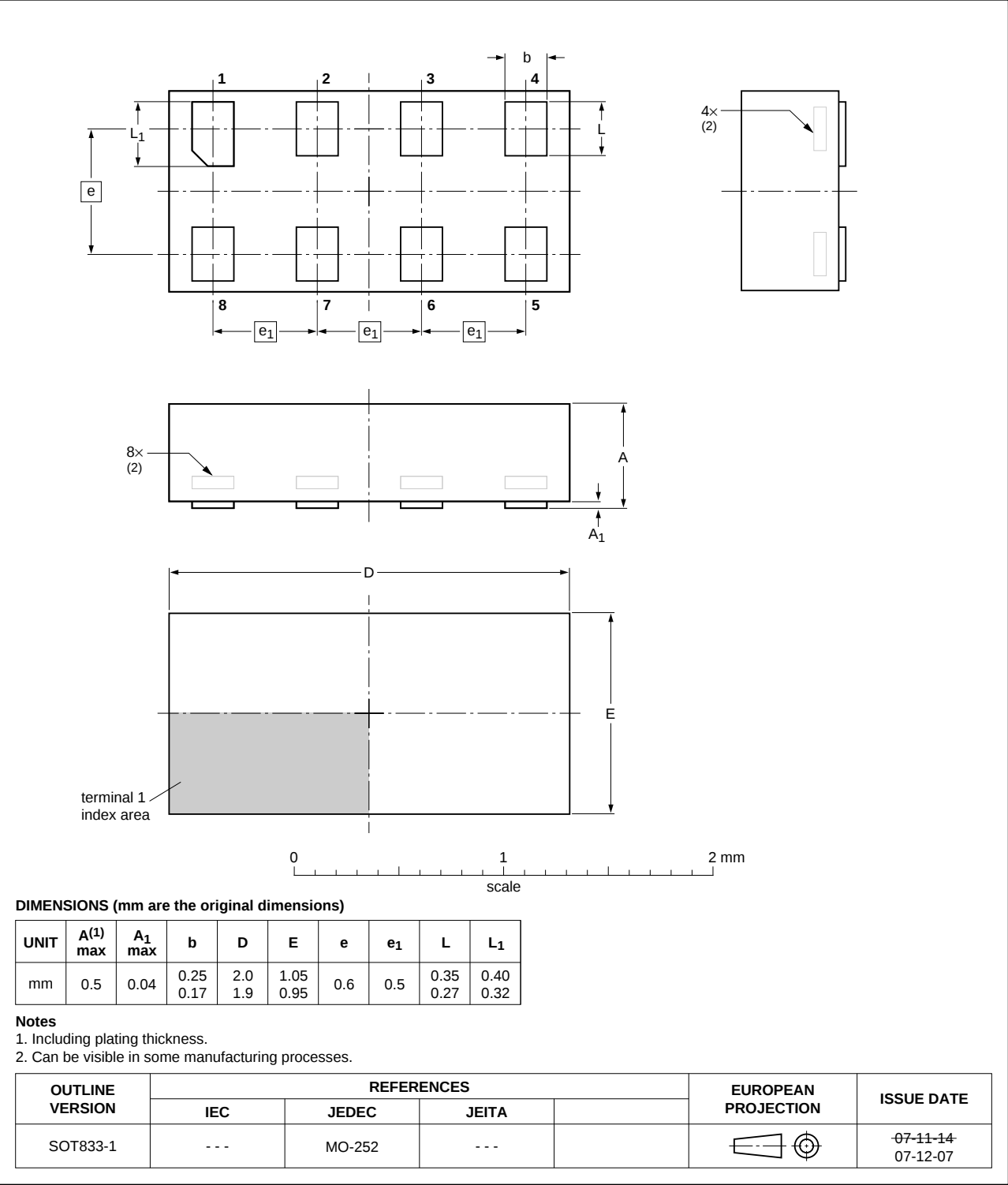


Fig 16. Package outline SOT833-1 (XSON8)

XQFN8: plastic, extremely thin quad flat package; no leads;
8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-2

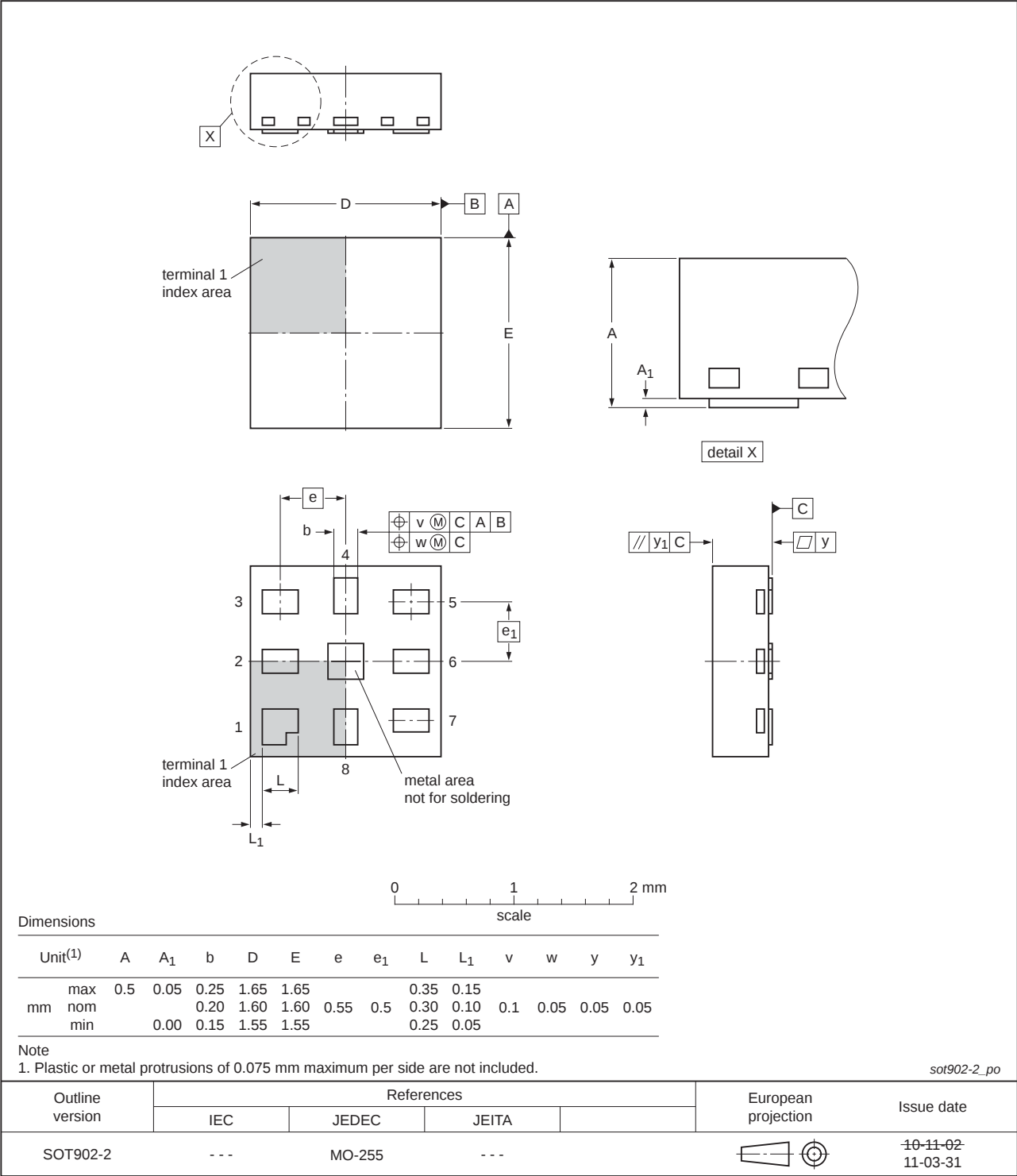


Fig 17. Package outline SOT902-2 (XQFN8)

15. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
ESD	ElectroStatic Discharge
FET	Field Effect Transistor
HBM	Human Body Model
PRR	Pulse Rate Repetition
TTL	Transistor-Transistor Logic

16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
CBTD3306 v.8	20120501	Product data sheet	-	CBTD3306 v.7
Modifications:	• For type number CBTD3306GM the SOT code has changed to SOT902-2.			
CBTD3306 v.7	20120103	Product data sheet	-	CBTD3306 v.6
Modifications:	• Marking code for type number CBTD3306D changed.			
CBTD3306 v.6	20111121	Product data sheet	-	CBTD3306 v.5
Modifications:	• Legal pages updated.			
CBTD3306 v.5	20110428	Product data sheet	-	CBTD3306 v.4
CBTD3306 v.4	20100325	Product data sheet	-	CBTD3306 v.3
CBTD3306 v.3	20100223	Product data sheet	-	CBTD3306 v.2
CBTD3306 v.2	20091015	Product data sheet	-	CBTD3306 v.1
CBTD3306 v.1	20011108	Product data	-	-

17. Legal information

17.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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